

Low offset voltage single channel operational amplifier circuit

Description

The OP07 chip is a low-noise, offset voltage trimmed, bipolar operational amplifier integrated circuit. Due to its very low input offset voltage (maximum offset voltage not exceeding $150\mu V$), the OP07 IC often does not require additional zero adjustment measures in many application scenarios.



Feature

- Ultra-low offset: maximum $150\mu V$
- Low input bias current: $1.8nA$
- Low offset voltage drift: $0.5\mu V/^{\circ}C$
- Ultra-stable, over time: maximum $2\mu V/month$
- Wide high power supply voltage range: $\pm 3V$ to $\pm 22V$

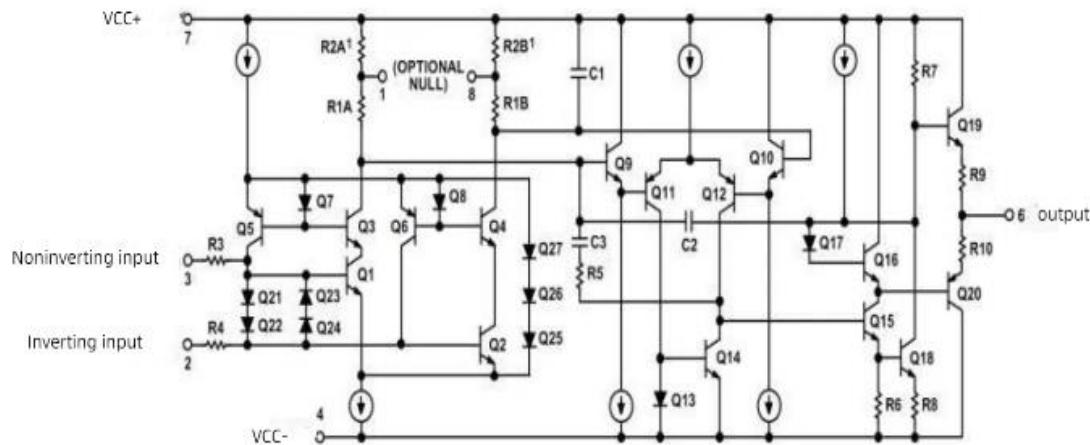


SOP-8 OP07

Application

- High-gain measuring equipment
- Amplifying weak signals from sensors
- Wireless base station control circuit

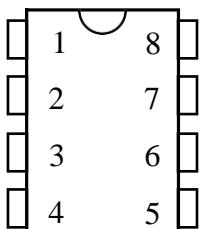
Internal Usage Diagram



OP07 Internal Structure Diagram

Pin Description

zeroing terminal 1



zeroing terminal 2

inverting input terminal

electric source

non-inverting input terminal

Output

ground

no-contact

OP07 Pin Diagram

Number	Symbol	Parameter
1	offsetnull 1	zeroing terminal 1(bias balance)
2	Inverting input	inverting input terminal
3	non- inverting input	non-inverting input
4	V _{cc} -	ground
5	nc	no-contact
6	output	output
7	V _{cc} +	electric source
8	offsetnull 2	zeroing terminal 2(bias balance)

Maximum ratings (Unless otherwise specified, $T_{amb}=25^{\circ}C$)

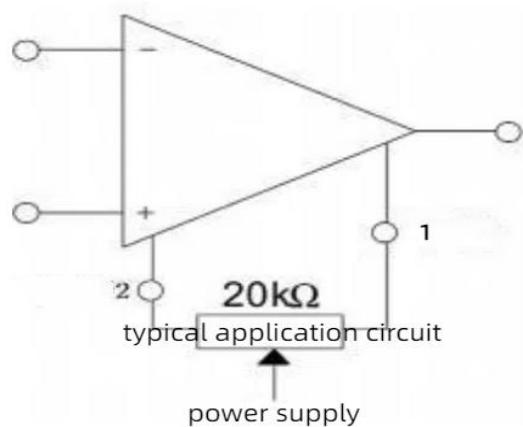
Parameter	Symbol	Value	Unit
supply voltage	V_{CC}	± 22	V
Differential input voltage	V_{IDR}	± 30	V
input voltage	V_i	± 22	V
Operating ambient temperature	T_{OPR}	-20 ~ +85	$^{\circ}C$
storage temperature	T_{STG}	-65 ~ +150	$^{\circ}C$

Electrical characteristics(Unless otherwise specified, $V_{CC+}=15V$, $V_{CC-}=ground$, $T_{amb}= 25^{\circ}C$)

Parameter	Symbol	Text Condition	Min	Typ	Max	Unit
Input offset voltage	V_{io}	$0^{\circ}C \leq T_{amb} \leq +105^{\circ}C$		60	150 250	μV
Long-term stability of input bias voltage				0.4	2	$\mu V/Mo$
Input offset voltage drift	D_{vio}			0.5	1.8	$\mu V/^{\circ}C$
Input offset current	I_{io}	$0^{\circ}C \leq T_{amb} \leq +105^{\circ}C$		0.8	6 7	nA
Input offset current drift	D_{lio}			15	50	$pA/^{\circ}C$
Input bias current drift	D_{lib}			15	50	$pA/^{\circ}C$
Open-loop output impedance	R_o			60		Ω
Differential input resistance	R_{id}			33		$M\Omega$
Common-mode input resistance	R_{ic}			120		$G\Omega$
Input common-mode voltage	V_{icm}	$0^{\circ}C \leq T_{amb} \leq +105^{\circ}C$	± 13 ± 13	± 13.5		V
Common-mode rejection ratio	C_{MR}	$0^{\circ}C \leq T_{amb} \leq +105^{\circ}C$	100 97	120		dB
Power supply rejection ratio	S_{VR}	$(V_{CC} = \pm 3 \text{to } \pm 18V)$ $0^{\circ}C \leq T_{amb} \leq +105^{\circ}C$	90 86	104		dB
Large signal voltage gain	A_{vd}	$V_{CC} = \pm 15$, $R_L=2K\Omega$, $V_O = \pm 10V$	120	400		V/mV
		$0^{\circ}C \leq T_{amb} \leq +105^{\circ}C$	100			
		$V_{CC} = \pm 3V$, $R_L = 500W$, $V_O = \pm 0.5V$	100	400		
Output voltage swing	V_{OPp}	$R_L = 10K\Omega$	± 12	± 13		V

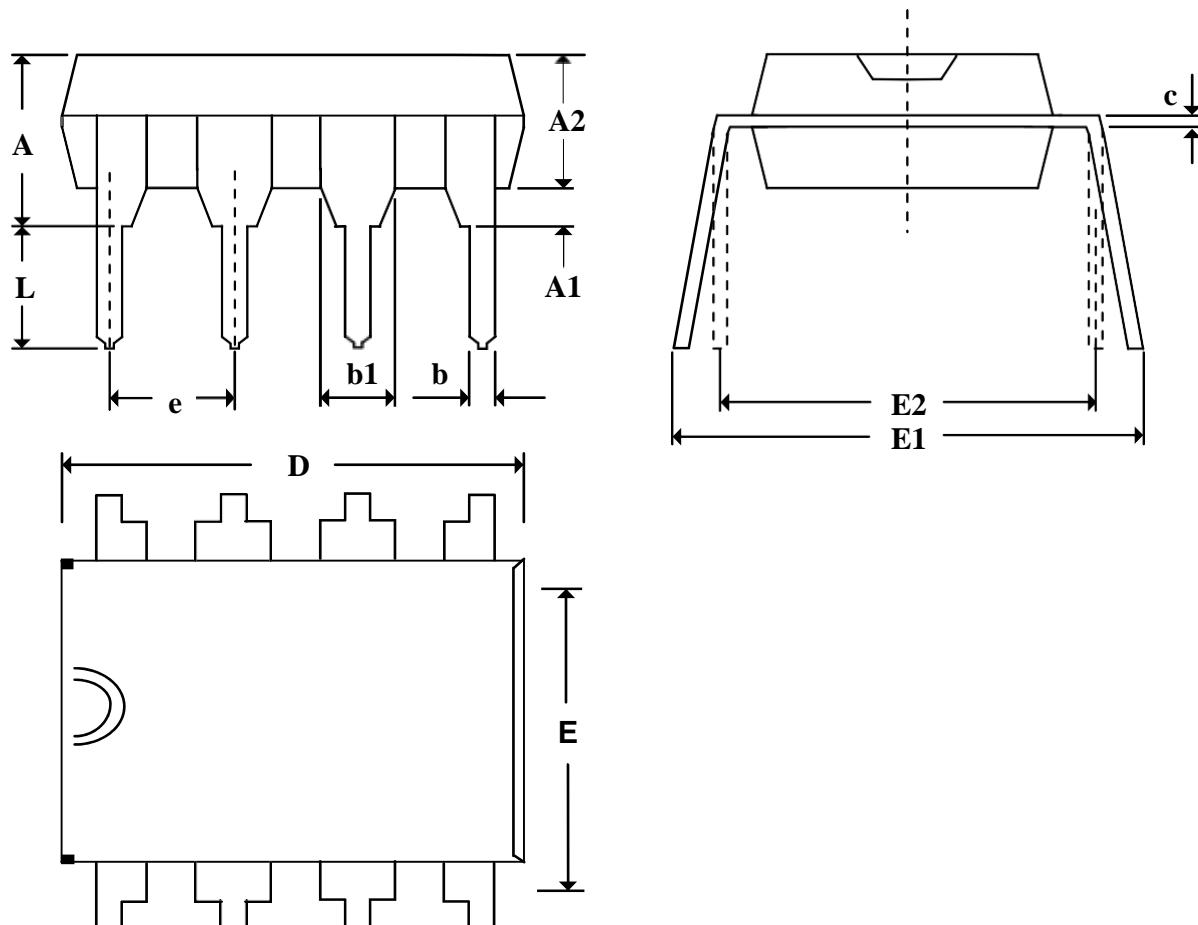
		$R_L = 2k\Omega$	± 11.5	± 12.8		
		$R_L = 1k\Omega$		± 12		
		$0^\circ C \leq T_{amb} \leq +70^\circ C, R_L = 2k\Omega$	± 11			
Conversion gain	S_R	$(R_L = 2k\Omega, C_L = 100PF)$		0.17		V/ μ S
Bandwidth gain	G_{BP}	$(R_L = 2k\Omega, C_L = 100PF, f = 100KHz)$		0.5		MHz
Power supply current	I_{cc}	no-load		2.7	5	mA
		$0^\circ C \leq T_{amb} \leq +105^\circ C$			6	
		$V_{CC} = \pm 3V$		0.67	1.3	
Equivalent input noise voltage	E_n	$f = 10Hz$		11	20	$\frac{nV}{\sqrt{Hz}}$
		$f = 100Hz$		10.5	13.5	
		$f = 1KHz$		10	11.5	
Equivalent input noise current	I_n	$f = 10Hz$		0.3	0.9	$\frac{pA}{\sqrt{Hz}}$
		$f = 100Hz$		0.2	0.3	
		$f = 1KHz$		0.1	0.2	

Typical Application Circuit



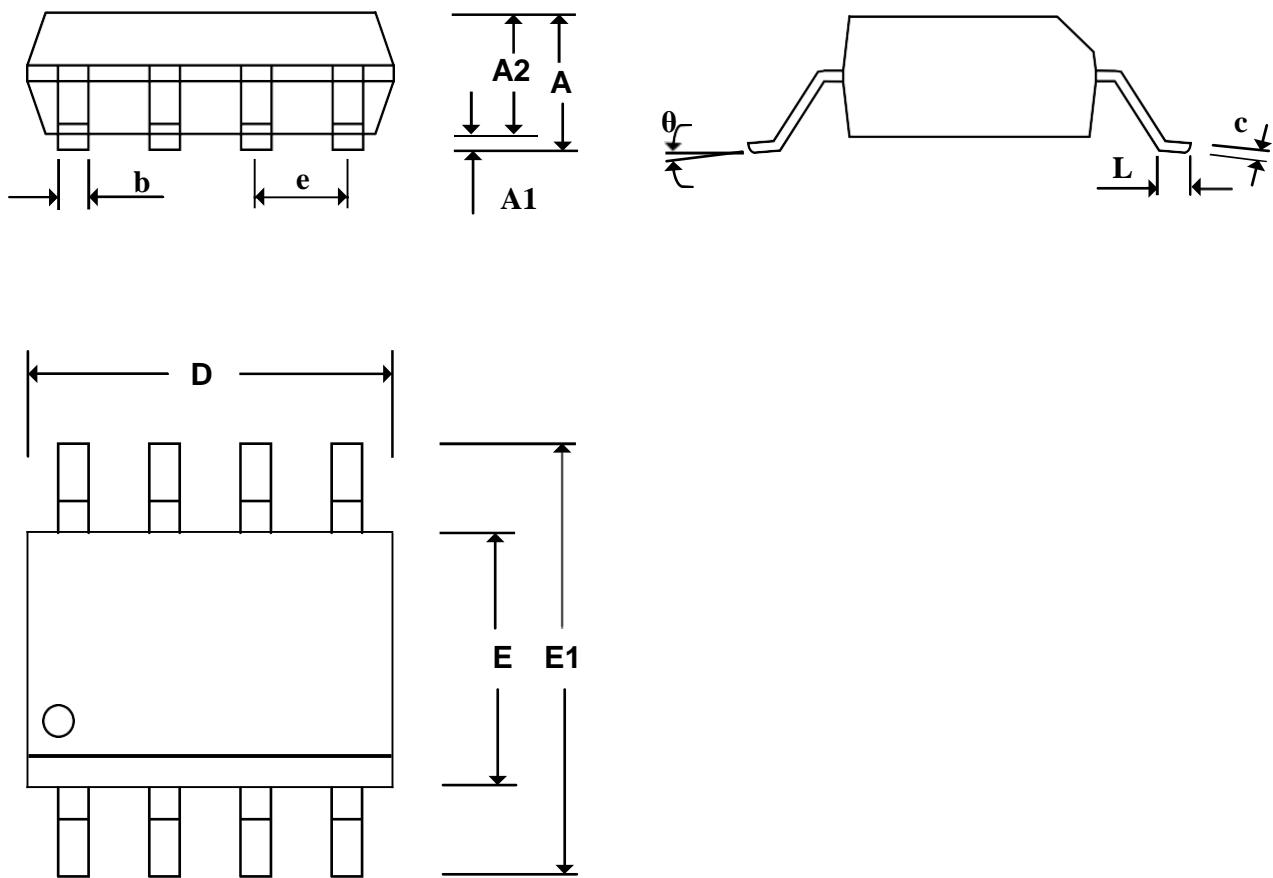
Package Outline Diagram

DIP-8



Symbol	Size(mm)		Symbol	Size(mm)	
	Min	Max		Min	Max
a	3.600	4.310	e	2.540	(bsc)
a1	0.510		d	9.000	9.450
a2	3.000	3.600	e	6.150	6.600
b	0.330	0.530	e1	7.870	9.610
b1	1.520 (bsc)		e2	7.320	7.920
c	0.204	0.360	l	3.000	3.600

SOP-8



Symbol	Size(mm)		Symbol	Size(mm)	
	Min	Max		Min	Max
a	1.350	1.800	d	4.700	5.100
a1	0.100	0.250	e	3.700	4.100
a2	1.250	1.550	e1	5.800	6.300
b	0.330	0.510	l	0.400	0.800
c	0.190	0.250	θ	0°	8°
e	1.270 (bsc)				